# **MA3X704** (MA704), **MA3X704A** (MA704A)

### Silicon epitaxial planar type

For switching

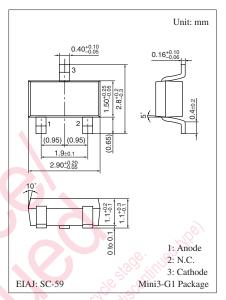
For wave detection

#### ■ Features

- $\bullet$  Low forward voltage  $V_F$  and good wave detection efficiency  $\eta$
- Small temperature coefficient of forward characteristic
- Small reverse current I<sub>R</sub>

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter		Symbol	Rating	Unit		
Reverse voltage	MA3X704	$V_R$	15	V		
	MA3X704A		30			
Maximum peak	MA3X704	V <sub>RM</sub>	15	V		
reverse voltage	MA3X704A		30			
Peak forward current		$I_{FM}$	150	mA		
Forward current		$I_{F}$	30	mA		
Junction temperature		Tj	125	°C		
Storage temperature		$T_{stg}$	-55 to +125	°C		

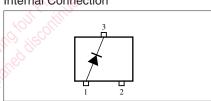


Marking Symbol

Note) The part numbers in the parenthesis show conventional part number.

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 MA3X704: M1K
 MA3X704A: M1L Internal Connection



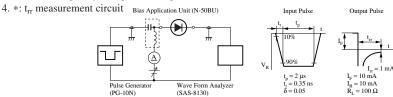
### ■ Electrical Characteristics $T_a = 25$ °C $\pm 3$ °C

Paramet	er	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage		$V_{F1}$	$I_F = 1 \text{ mA}$			0.4	V
		$V_{F2}$	$I_F = 30 \text{ mA}$			1.0	
Reverse current	MA3X704	I <sub>R</sub>	$V_R = 15 \text{ V}$			200	nA
	MA3X704A	Call?	$V_R = 30 \text{ V}$			300	
Terminal capacitance		Ct	$V_R = 1 \text{ V, f} = 1 \text{ MHz}$		1.5		pF
Reverse recovery tim	e *	t <sub>rr</sub>	$I_F = I_R = 10 \text{ mA}$		1.0		ns
		" Wgr.	$I_{rr} = 1 \text{ mA}, R_L = 100 \Omega$				
Detection efficiency	Ç	η	$V_{IN} = 3 V_{(peak)}$ , $f = 30 MHz$		65		%
			$R_L = 3.9 \text{ k}\Omega, C_L = 10 \text{ pF}$				

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
  - 2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.
  - 3. Absolute frequency of input and output is 2 GHz.

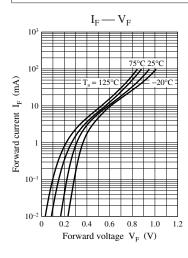
 $R_{\circ} = 50 \Omega$ 

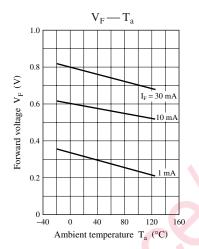
Publication date: April 2004



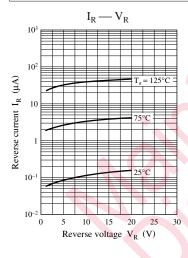
 $R_i = 50 \Omega$ 

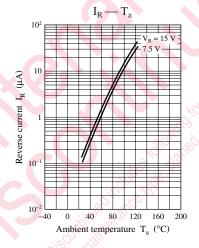
### Common characteristics charts

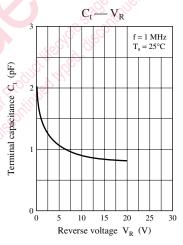




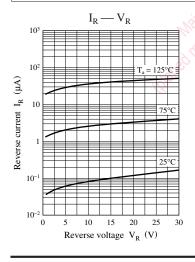
### Characteristics charts of MA3X704

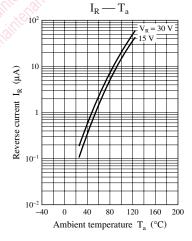


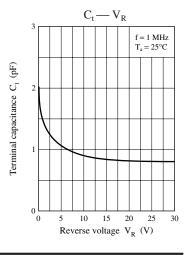




### Characteristics charts of MA3X704A







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